

TPS22995 5.5-V, 3.8-A, 18-mΩ On-Resistance Load Switch with Adjustable Rise Time

1 Features

- Input operating voltage range (V_{IN}): 0.4 V – 5.5 V
- Bias voltage supply (V_{BIAS}): 1.5 V – 5.5 V
- Maximum continuous current: 3.8 A
- On-resistance (R_{ON}): 18 mΩ (typ.)
- Adjustable slew rate control through external capacitor
- Quick Output Discharge (QOD): 100 Ω (typ.)
- Thermal shutdown
- Smart ON pin pulldown ($R_{PD,ON}$):
 - ON $\geq V_{IH}$ (I_{ON}): 25 nA (max.)
 - ON $\leq V_{IL}$ ($R_{PD,ON}$): 500 kΩ (typ.)
- Low power consumption:
 - ON state (I_Q): 10 μA (typ.)
 - OFF state (I_{SD}): 0.1 μA (typ.)

2 Applications

- [Notebook PC](#)
- [Tablets](#)
- Industrial PC
- Discrete industrial solutions

3 Description

The TPS22995 is a single-channel load switch that provides a configurable rise time to minimize inrush current. The device contains an N-channel MOSFET that can operate over an input voltage range of 0.4 V to 5.5 V and can support a maximum continuous current of 3.8 A.

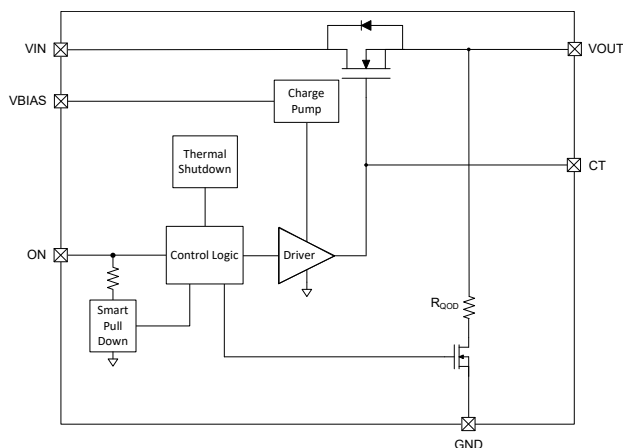
The switch is controlled by an on and off input (ON), which is capable of interfacing directly with low voltage control signals. The TPS22995 also has a Quick Output Discharge when the switch is turned off, pulling the output voltage down to a known 0-V state.

The TPS22995 is available in two different 6-pin WQFN packages with both 0.4-mm and 0.5-mm options. The device is characterized for operation over the free-air temperature range of -40°C to $+125^{\circ}\text{C}$.

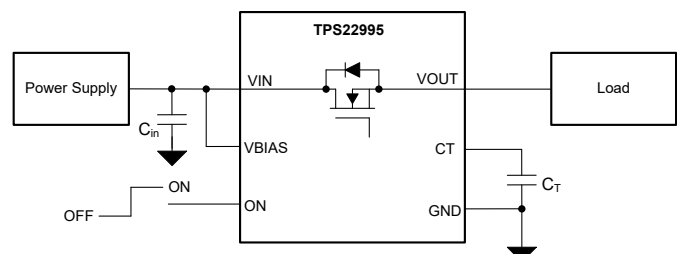
Package Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)
TPS22995	RZF (WQFN, 6)	1.25 × 0.85 mm
	RZG (WQFN, 6)	1.50 × 0.75 mm

- (1) For all available packages, see the orderable addendum at the end of the data sheet.



TPS22995 Block Diagram



Typical Application Diagram



Table of Contents

1 Features	1	8.1 Overview.....	13
2 Applications	1	8.2 Functional Block Diagram.....	13
3 Description	1	8.3 Feature Description.....	14
4 Revision History	2	8.4 Device Functional Modes.....	15
5 Pin Configuration and Functions	3	9 Application and Implementation	16
6 Specifications	4	9.1 Application Information.....	16
6.1 Absolute Maximum Ratings.....	4	9.2 Typical Application.....	16
6.2 ESD Ratings.....	4	9.3 Power Supply Recommendations.....	17
6.3 Recommended Operating Conditions.....	4	9.4 Layout.....	18
6.4 Thermal Information.....	4	10 Device and Documentation Support	19
6.5 Electrical Characteristics (VBIAS = 5 V).....	5	10.1 Receiving Notification of Documentation Updates..	19
6.6 Electrical Characteristics (VBIAS = 3.3 V).....	5	10.2 Support Resources.....	19
6.7 Electrical Characteristics (VBIAS = 1.5 V).....	6	10.3 Trademarks.....	19
6.8 Switching Characteristics (VBIAS = 5 V).....	7	10.4 Electrostatic Discharge Caution.....	19
6.9 Switching Characteristics (VBIAS = 3.3 V).....	8	10.5 Glossary.....	19
6.10 Switching Characteristics (VBIAS = 1.5 V).....	8	11 Mechanical, Packaging, and Orderable	
6.11 Typical Characteristics.....	10	Information	19
7 Parameter Measurement Information	12	11.1 Tape and Reel Information.....	20
8 Detailed Description	13		

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
December 2022	*	Initial Release

5 Pin Configuration and Functions

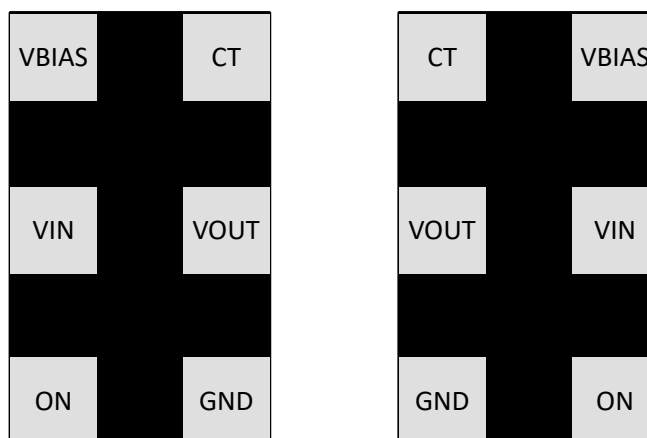


Figure 5-1. TPS22995 RZF, RZG 6-Pin WQFN Package (Top View Left, Bottom View Right)

Table 5-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
VBIAS	1	P	Bias voltage
VIN	2	P	Supply input
ON	3	I	Enable pin
GND	4	G	Ground
VOUT	5	P	Output voltage
CT	6	I	Timing pin, can control the slew rate of the output through a capacitor to GND

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V_{IN}	Input Voltage	−0.3	6	V
V_{BIAS}	Bias Voltage	−0.3	6	V
V_{ON}, V_{PG}, V_{QOD}	Control Pin Voltage	−0.3	6	V
V_{CT}	CT Pin Voltage		15	V
I_{MAX}	Maximum Current		3.8	A
T_J	Junction temperature		Internally Limited	°C
T_{stg}	Storage temperature	−65	150	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Input Voltage	0.4		5.5	V
V_{BIAS}	Bias Voltage	1.5		5.5	V
V_{IH}	ON Pin High Voltage Range	0.8		5.5	V
V_{IL}	ON Pin Low Voltage Range	0		0.35	V
T_A	Ambient Temperature	−40		125	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS22995		UNIT
		6 PINS		
		RZF(WQFN-HR)	RZG(WQFN-HR)	
R _{θJA}	Junction-to-ambient thermal resistance	143.5	141.6	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	132.1	133.7	°C/W
R _{θJB}	Junction-to-board thermal resistance	47.8	41.2	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	5.2	5.3	°C/W
Y _{JB}	Junction-to-board characterization parameter	47.4	40.8	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics (VBIAS = 5 V)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
Power Consumption							
I _{SD,VBIAS}	VBIAS Shutdown Current	ON = 0V	25 °C	0.1			uA
			—40 °C to 85 °C	0.5		uA	
			—40 °C to 125 °C	1		uA	
I _{Q,VBIAS}	VBIAS Quiescent Current	ON > V _{IH}	25 °C	10			uA
			—40 °C to 85 °C	20		uA	
			—40 °C to 125 °C	20		uA	
I _{SD,VIN}	VIN Shutdown Current	ON = 0V	25 °C	0.1			uA
			—40 °C to 85 °C	1		uA	
			—40 °C to 125 °C	2		uA	
I _{ON}	ON pin leakage	ON = VBIAS	—40 °C to 125 °C	0.1			uA
Performance							
R _{ON}	On-Resistance	VIN = 5V, I _{OUT} =-200mA	25 °C	18			mΩ
			—40 °C to 85 °C	24		mΩ	
			—40 °C to 125 °C	27		mΩ	
		VIN = 3.3V, I _{OUT} =-200mA	25 °C	17			mΩ
			—40 °C to 85 °C	23		mΩ	
			—40 °C to 125 °C	25		mΩ	
		VIN = 1.8V, I _{OUT} =-200mA	25 °C	17			mΩ
			—40 °C to 85 °C	23		mΩ	
			—40 °C to 125 °C	25		mΩ	
		VIN = 1.2V, I _{OUT} =-200mA	25 °C	17			mΩ
			—40 °C to 85 °C	23		mΩ	
			—40 °C to 125 °C	25		mΩ	
VIN = 0.8V, I _{OUT} =-200mA	25 °C	17			mΩ		
	—40 °C to 85 °C	23		mΩ			
	—40 °C to 125 °C	25		mΩ			
R _{PD,ON}	Smart Pull Down Resistance	ON < V _{IL}	25 °C	500			kΩ
			—40 °C to 125 °C	1000		kΩ	
R _{QOD}	QOD Resistance		25 °C	100			Ω
			—40 °C to 125 °C	150		Ω	
Protection							
TSD	Thermal Shutdown		-	150	170	190	°C
TSD _{HYS}	Thermal Shutdown Hysteresis		-	20			°C

6.6 Electrical Characteristics (VBIAS = 3.3 V)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
Power Consumption							
I _{SD,VBIAS}	VBIAS Shutdown Current	ON = 0V	25 °C		0.1		uA
			—40 °C to 85 °C			0.5	uA
			—40 °C to 125 °C			1	uA

6.6 Electrical Characteristics (VBIAS = 3.3 V) (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
I _{Q,VBIAS}	VBIAS Quiescent Current	ON > V _{IH}	25 °C	10			uA
			—40 °C to 85 °C	20			uA
			—40 °C to 125 °C	20			uA
I _{SD,VIN}	VIN Shutdown Current	ON = 0V	25 °C	0.1			uA
			—40 °C to 85 °C	1			uA
			—40 °C to 125 °C	2			uA
I _{ON}	ON pin leakage	ON = VBIAS	—40 °C to 125 °C	0.1			uA
Performance							
R _{ON}	On-Resistance	VIN = 3.3V, , I _{OUT} =-200mA	25 °C	18			mΩ
			—40 °C to 85 °C	24			mΩ
			—40 °C to 125 °C	27			mΩ
		VIN = 1.8V, , I _{OUT} =-200mA	25 °C	17			mΩ
			—40 °C to 85 °C	23			mΩ
			—40 °C to 125 °C	25			mΩ
		VIN = 1.2V, I _{OUT} =-200mA	25 °C	17			mΩ
			—40 °C to 85 °C	23			mΩ
			—40 °C to 125 °C	25			mΩ
		VIN = 0.8V, I _{OUT} =-200mA	25 °C	17			mΩ
			—40 °C to 85 °C	23			mΩ
			—40 °C to 125 °C	25			mΩ
R _{PD,ON}	Smart Pull Down Resistance	ON < V _{IL}	25 °C	500			kΩ
			—40 °C to 125 °C	1000			kΩ
R _{QOD}	QOD Resistance		25 °C	100			Ω
			—40 °C to 125 °C	150			Ω
Protection							
TSD	Thermal Shutdown		-	150	170	190	°C
TSD _{HYS}	Thermal Shutdown Hysteresis		-	20			°C

6.7 Electrical Characteristics (VBIAS = 1.5 V)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
Power Consumption							
I _{SD,VBIAS}	VBIAS Shutdown Current	ON = 0V	25 °C		0.1		uA
			—40 °C to 85 °C			0.5	uA
			—40 °C to 125 °C			1	uA
I _{Q,VBIAS}	VBIAS Quiescent Current	ON > V _{IH}	25 °C		10		uA
			—40 °C to 85 °C			20	uA
			—40 °C to 125 °C			20	uA
I _{SD,VIN}	VIN Shutdown Current	ON = 0V	25 °C		0.1		uA
			—40 °C to 85 °C			1	uA
			—40 °C to 125 °C			2	uA
I _{ON}	ON pin leakage	ON = VBIAS	—40 °C to 125 °C		0.1		uA
Performance							

6.7 Electrical Characteristics (VBIAS = 1.5 V) (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T _A	MIN	TYP	MAX	UNIT
R _{ON}	On-Resistance	VIN = 1.5V, I _{OUT} =-200mA	25 °C		20		mΩ
			−40 °C to 85 °C			33	mΩ
			−40 °C to 125 °C			37	mΩ
		VIN = 1.2V, I _{OUT} =-200mA	25 °C		20		mΩ
			−40 °C to 85 °C			31	mΩ
			−40 °C to 125 °C			34	mΩ
		VIN = 0.8V, I _{OUT} =-200mA	25 °C		20		mΩ
			−40 °C to 85 °C			31	mΩ
			−40 °C to 125 °C			34	mΩ
R _{PD,ON}	Smart Pull Down Resistance	ON < V _{IL}	25 °C		500		kΩ
			−40 °C to 125 °C			1000	kΩ
R _{QOD}	QOD Resistance		25 °C		110		Ω
			−40 °C to 125 °C			150	Ω
Protection							
TSD	Thermal Shutdown	Rising	-	150	170	190	°C
		Hysteresis	-		20		°C

6.8 Switching Characteristics (VBIAS = 5 V)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VIN = 5V						
t _{ON}	Turn ON time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		2810		us
t _{RISE}	Rise time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		2020		us
t _D	Delay time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		791		us
t _{FALL}	Fall time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		1110		us
t _{OFF}	Turn OFF time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		62.7		us
VIN = 3.3V						
t _{ON}	Turn ON time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		1580		us
t _{RISE}	Rise time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		1350		us
t _D	Delay time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		561		us
t _{FALL}	Fall time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		1100		us
t _{OFF}	Turn OFF time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		63		us
VIN = 1.8V						
t _{ON}	Turn ON time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		1110		us
t _{RISE}	Rise time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		754		us
t _D	Delay time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		523		us
t _{FALL}	Fall time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		1100		us
t _{OFF}	Turn OFF time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		63		us
VIN = 1.2V						
t _{ON}	Turn ON time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		928		us
t _{RISE}	Rise time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		516		us
t _D	Delay time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		508		us
t _{FALL}	Fall time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		1100		us
t _{OFF}	Turn OFF time	R _L = 100Ω, C _L = 10uF, CT = 1000pF		63		us

6.8 Switching Characteristics (VBIAS = 5 V) (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VIN = 0.8V						
tON	Turn ON time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		796		us
tRISE	Rise time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		360		us
tD	Delay time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		499		us
tFALL	Fall time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1100		us
tOFF	Turn OFF time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		63		us

6.9 Switching Characteristics (VBIAS = 3.3 V)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VIN = 3.3V						
tON	Turn ON time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		2110		us
tRISE	Rise time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1370		us
tD	Delay time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		741		us
tFALL	Fall time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1110		us
tOFF	Turn OFF time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		61.8		us
VIN = 1.8V						
tON	Turn ON time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1170		us
tRISE	Rise time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		625		us
tD	Delay time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		543		us
tFALL	Fall time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1100		us
tOFF	Turn OFF time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		63		us
VIN = 1.2V						
tON	Turn ON time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		971		us
tRISE	Rise time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		443		us
tD	Delay time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		528		us
tFALL	Fall time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1100		us
tOFF	Turn OFF time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		63		us
VIN = 0.8V						
tON	Turn ON time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		832		us
tRISE	Rise time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		315		us
tD	Delay time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		516		us
tFALL	Fall time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1100		us
tOFF	Turn OFF time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		63		us

6.10 Switching Characteristics (VBIAS = 1.5 V)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VIN = 1.5V						
tON	Turn ON time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1350		us
tRISE	Rise time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		653		us
tD	Delay time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		693		us
tFALL	Fall time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1190		us

6.10 Switching Characteristics (VBIAS = 1.5 V) (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
tOFF	Turn OFF time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		63.6		us
VIN = 1.2V						
tON	Turn ON time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1020		us
tRISE	Rise time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		457		us
tD	Delay time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		567		us
tFALL	Fall time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1100		us
tOFF	Turn OFF time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		60		us
VIN = 0.8V						
tON	Turn ON time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		885		us
tRISE	Rise time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		331		us
tD	Delay time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		553		us
tFALL	Fall time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		1100		us
tOFF	Turn OFF time	$R_L = 100\Omega$, $C_L = 10\mu\text{F}$, $C_T = 1000\text{pF}$		60		us

6.11 Typical Characteristics

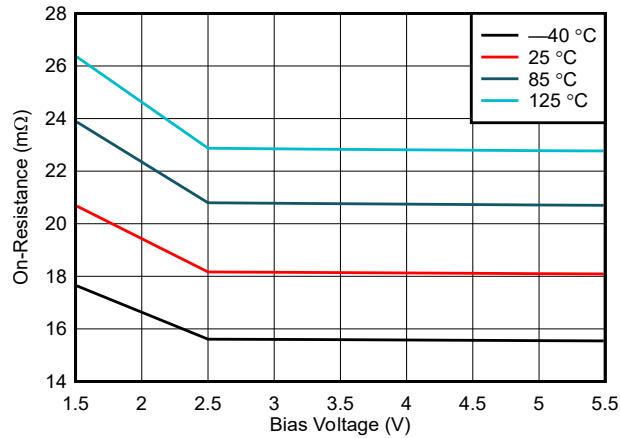


Figure 6-1. On-Resistance vs Bias Voltage

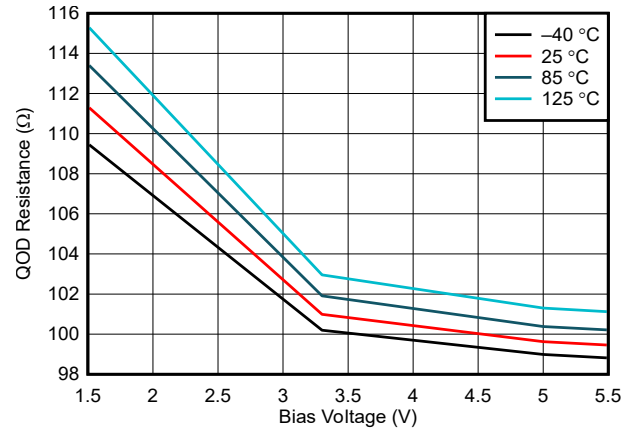


Figure 6-2. QOD Resistance vs Bias Voltage

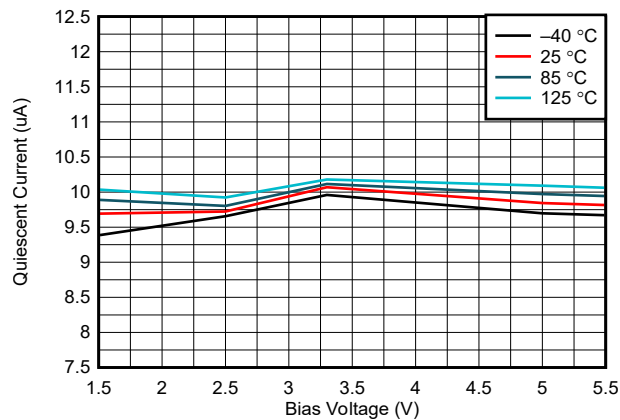


Figure 6-3. Quiescent Current vs Bias Voltage

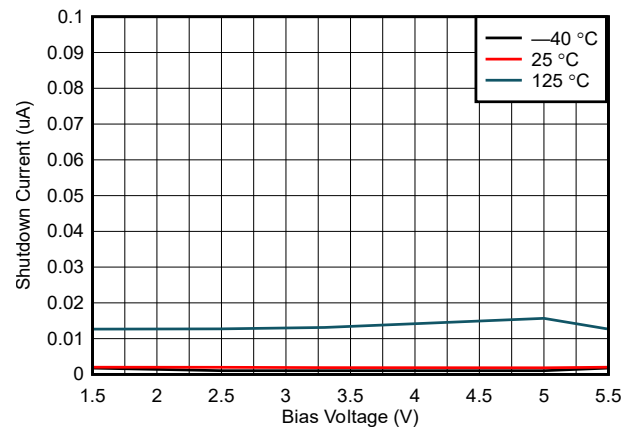


Figure 6-4. VBIAS Shutdown Current vs Bias Voltage

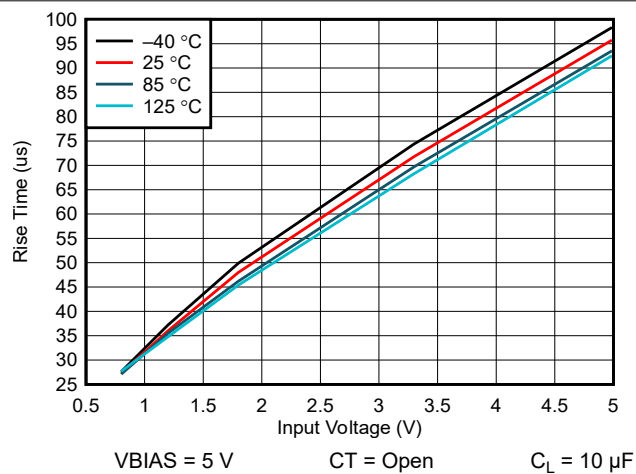


Figure 6-5. Rise Time vs Input Voltage

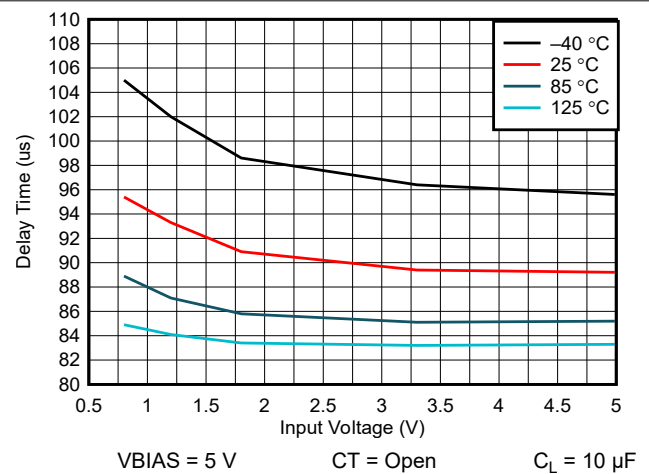


Figure 6-6. Delay Time vs Input Voltage

6.11 Typical Characteristics (continued)

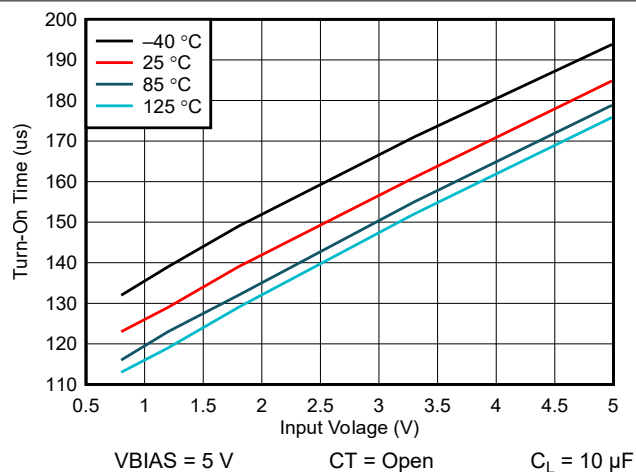


Figure 6-7. Turn-On Time vs Input Voltage

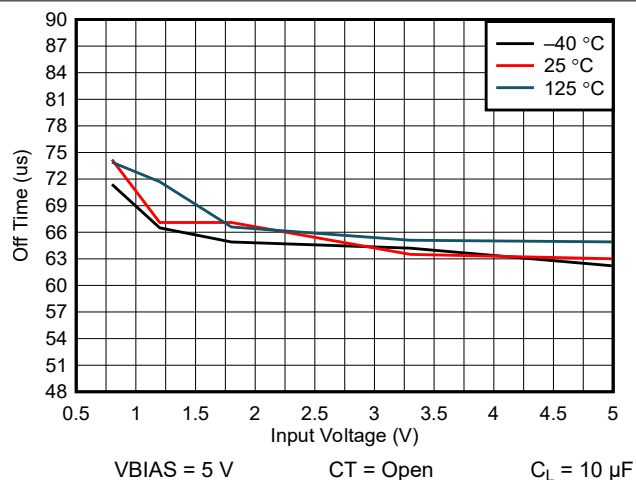


Figure 6-8. Off Time vs Input Voltage

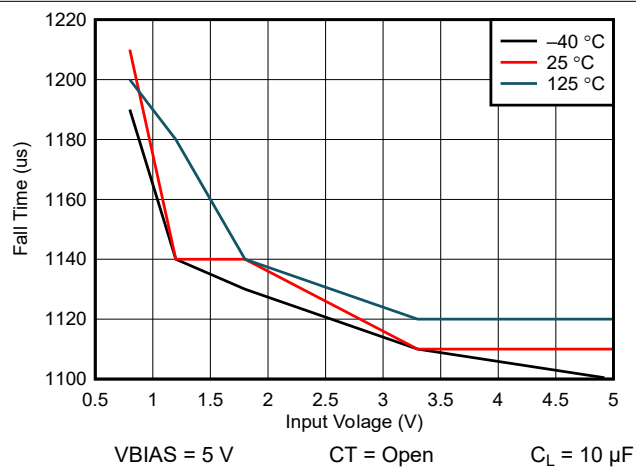


Figure 6-9. Fall Time vs Input Voltage

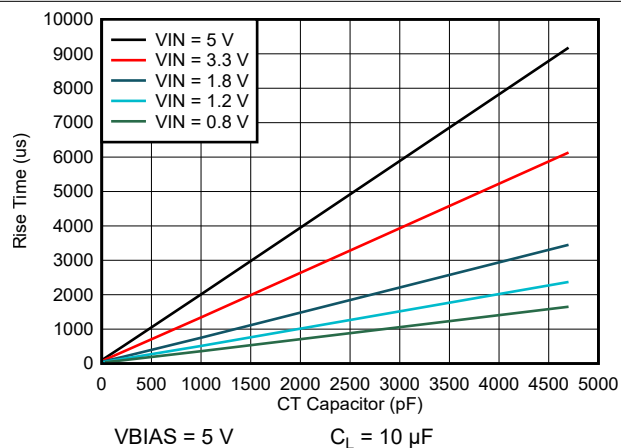


Figure 6-10. Rise Time vs CT Capacitor

7 Parameter Measurement Information

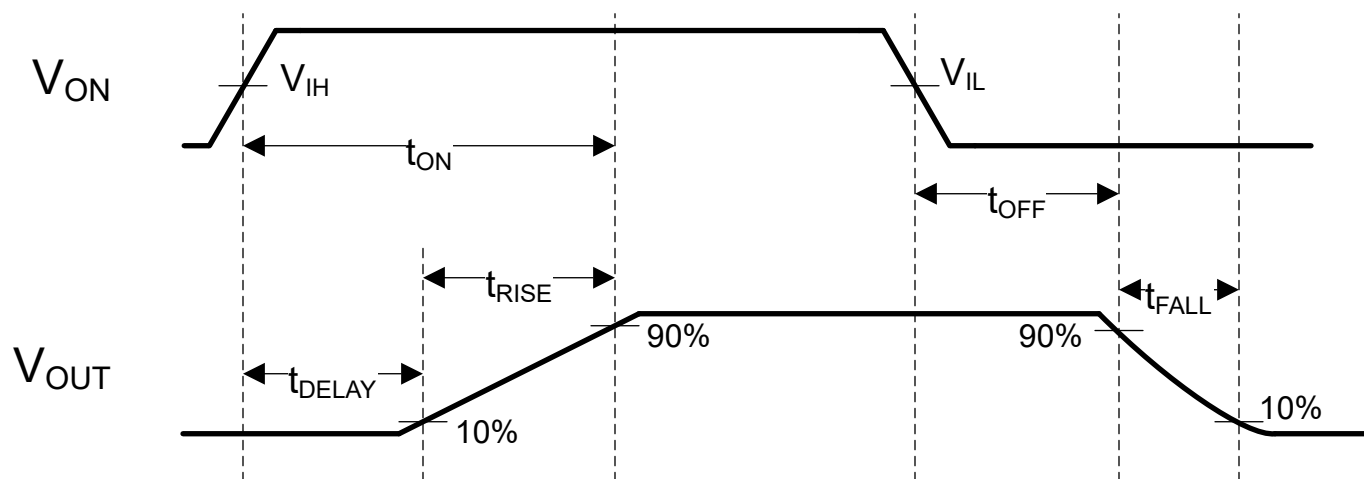


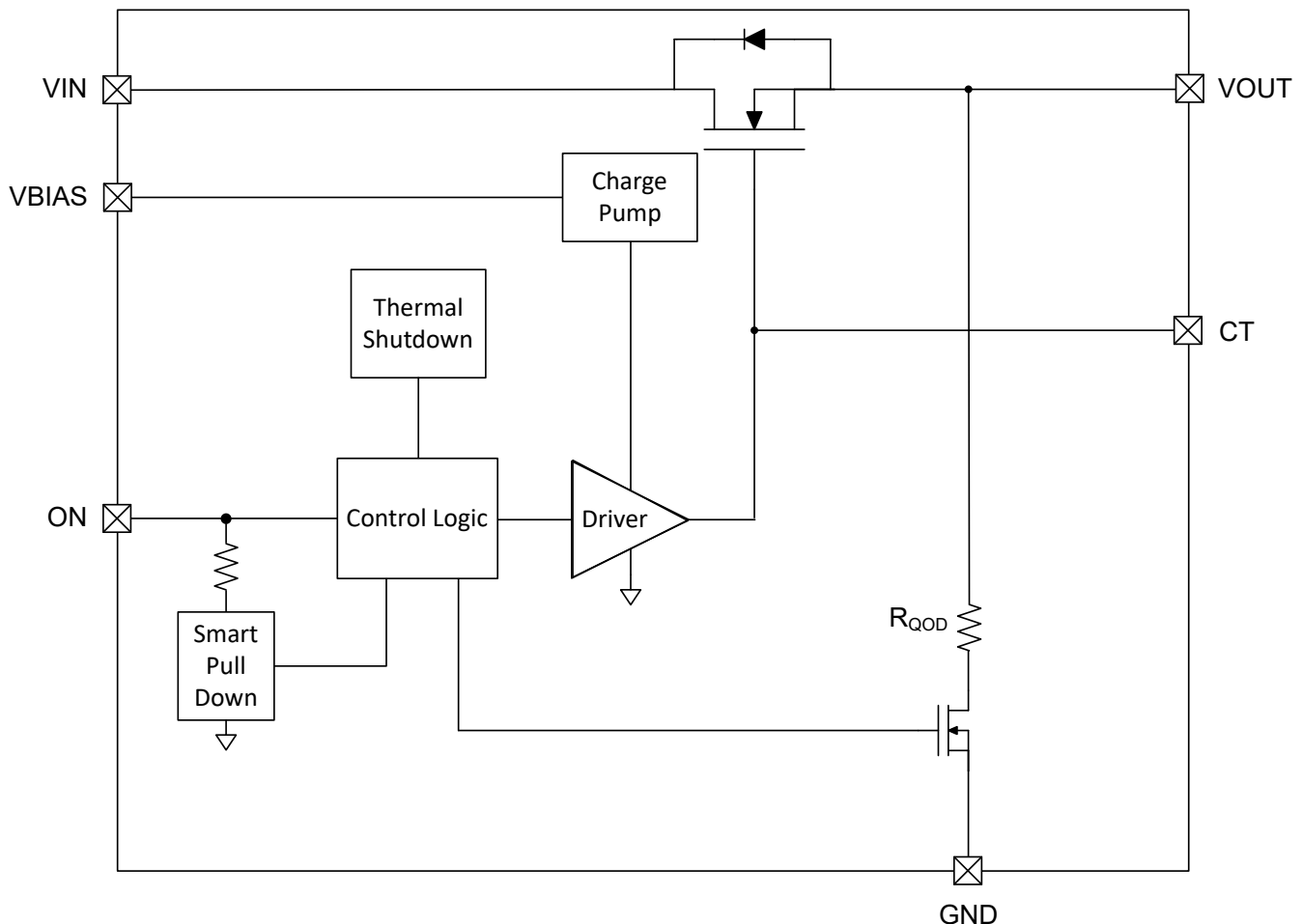
Figure 7-1. TPS22995 Timing Parameters

8 Detailed Description

8.1 Overview

The TPS22995 is a 5.5-V, 3.8-A load switch in a 6-pin WQFN package with 0.4-mm and 0.5-mm pin pitch options. To reduce voltage drop for low voltage and high-current rails, the device implements a low-resistance, 18-m Ω , N-channel MOSFET, which reduces the dropout voltage through the device. The device has a configurable slew rate, which helps reduce or eliminate power supply droop because of large inrush currents. The slew rate can be configured by connecting a capacitor to ground to the CT pin. The TPS22995 also integrates a Quick Output Discharge circuit that is activated when the switch is turned off, pulling the output voltage down to a known 0-V state. TPS22995 increases circuit robustness by integrating thermal shutdown that protects the device in high-temperature conditions.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Adjustable Slew Rate

A capacitor to GND on the CT pin sets the slew rate, and the higher the Capacitor the higher the slew rate. Rise times are shown below.

Table 8-1. Rise Time vs CT vs V_{IN}

CT Capacitor	V _{IN} = 5.5 V	V _{IN} = 3.3 V	V _{IN} = 1.8 V	V _{IN} = 1.2 V	V _{IN} = 0.8 V
0 pF	96.2 μs	72.2 μs	47.8 μs	36.6 μs	28.2 us
220 pF	517 μs	350 μs	201 μs	140 μs	100 us
1000 pF	2020 μs	1350 μs	754 μs	516 μs	360 us
4700 pF	9230 μs	6190 μs	3470 μs	2380 μs	1660 us

The following equation can be used to estimate the rise time for different V_{IN} and CT capacitors:

$$t_R = (0.3418V_{IN} + 0.1036) \times CT + 14.064V_{IN} + 12.255 \quad (1)$$

where

- t_R = Rise time in μs.
- V_{IN} = Input voltage in V.
- CT = CT Capacitor in pF.

8.3.2 Quick Output Discharge

TPS22995 integrates Quick Output Discharge. When the switch is disabled, a discharge resistor is connected between V_{OUT} and GND. This resistor has a typical value of 100 Ω and prevents the output from floating while the switch is disabled

8.3.3 ON and OFF Control

The ON pin controls the state of the switch. The ON pin is compatible with standard GPIO logic threshold so it can be used in a wide variety of applications. When power is first applied to V_{IN}, a Smart Pulldown is used to keep the ON pin from floating until the system sequencing is complete. After the ON pin is deliberately driven high ($\geq V_{IH}$), the Smart Pulldown is disconnected to prevent unnecessary power loss. See the below table when the ON Pin Smart Pulldown is active.

Table 8-2. On Pin Control

ON Pin Voltage	ON Pin Function
$\leq V_{IL}$	Pulldown active
$\geq V_{IH}$	No pulldown

8.3.4 Thermal Shutdown

When the device temperature reaches 170°C (typical), the device shuts itself off to prevent thermal damage. After the device cools off by about 20°C, it turns back on. If the device is kept in a thermally stressful environment, then the device oscillates between these two states until it can keep its temperature below the thermal shutdown point.

8.4 Device Functional Modes

Table 8-3. Device Functional Modes

ON	Fault Condition	VOUT State
L	N/A	Hi-Z
H	None	V_{IN} through R_{ON}
X	Thermal shutdown	Hi-Z

9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The input to output voltage drop in the device is determined by the R_{ON} of the device and the load current. The R_{ON} of the device depends upon the V_{IN} and V_{BIAS} condition of the device. See the R_{ON} specification in the [Section 6.5](#) table of this data sheet. After the R_{ON} of the device is determined based upon the V_{IN} and V_{BIAS} conditions, use the below equation to calculate the input to output voltage drop.

$$\Delta V = I_{LOAD} \times R_{ON} \quad (2)$$

where

- ΔV is the voltage drop from V_{IN} to V_{OUT} .
- I_{LOAD} is the load current.
- R_{ON} is the on-resistance of the device for a specific V_{IN} and V_{BIAS} .
- An appropriate I_{LOAD} must be chosen such that the I_{MAX} specification of the device is not violated.

9.2 Typical Application

This typical application demonstrates how the TPS22995 device can be used to limit start-up inrush current.

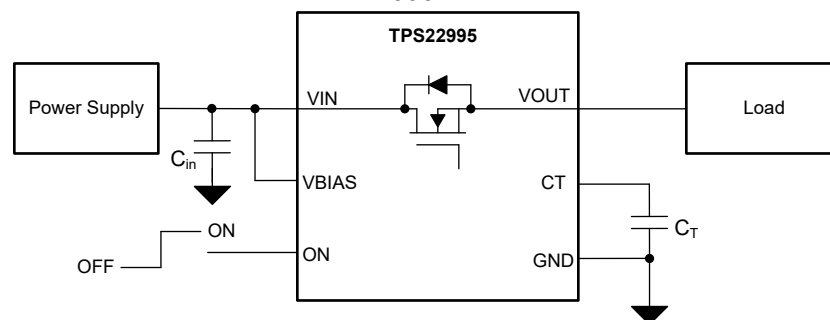


Figure 9-1. TPS22995 Application Schematic

9.2.1 Design Requirements

Table 9-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
V_{BIAS}	5.5 V
V_{IN}	5.5 V
C_L	47 μ F
R_L	None
Maximum acceptable inrush current	200 mA

9.2.2 Detailed Design Procedure

When the switch is enabled, the output capacitors must be charged up from 0 V to V_{IN} . This charge arrives in the form of inrush current. Use the equation below to calculate inrush current.

$$I_{INRUSH} = C_L \times dVOUT/dt \quad (3)$$

where

- C_L is the output capacitance.
- $dVOUT$ is the change in $VOUT$ during the ramp-up of the output voltage when device is enabled.
- dt is the rise time in $VOUT$ during the ramp-up of the output voltage when the device is enabled.

The TPS22995 offers an adjustable rise time for $VOUT$, allowing the user to control the inrush current during turn-on. The appropriate rise time can be calculated using the design requirements and the inrush current equation as shown below.

$$200 \text{ mA} = 47\mu\text{F} \times 5.5 \text{ V}/dt \quad (4)$$

where

$$dt = 1292 \text{ us} \quad (5)$$

The TPS22995 has very fast rise times with CT pin open. The typical rise time is 127 μs at $V_{BIAS} = 5.5 \text{ V}$, $V_{IN} = 5.5 \text{ V}$, $R_L = 100 \Omega$, and $C_L = 0.1 \mu\text{F}$. This rise time results in an inrush current of 1.59 A. According to [Table 8-1](#), using $R_T = 10 \text{ k}\Omega$ results in a rise time of 1520 μs , which limits the inrush current to 176 mA. Alternatively, can be used to determine the capacitor needed.

9.2.3 Application Performance Plots

The below oscilloscope captures show the difference between the inrush current for $CT = 0 \text{ pF}$ and $CT = 1000 \text{ pF}$ settings. The $CT = 1000 \text{ pF}$ setting is able to keep the inrush current under the required 200 mA, while the $CT = 0 \text{ pF}$ setting is too fast for this design.

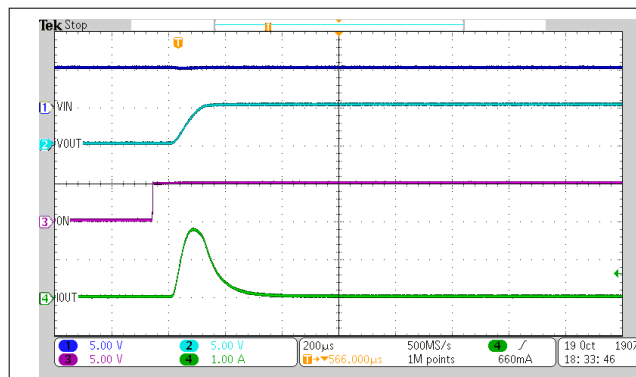


Figure 9-2. Inrush Current for $C_L = 47 \mu\text{F}$ with $CT = 0 \text{ pF}$

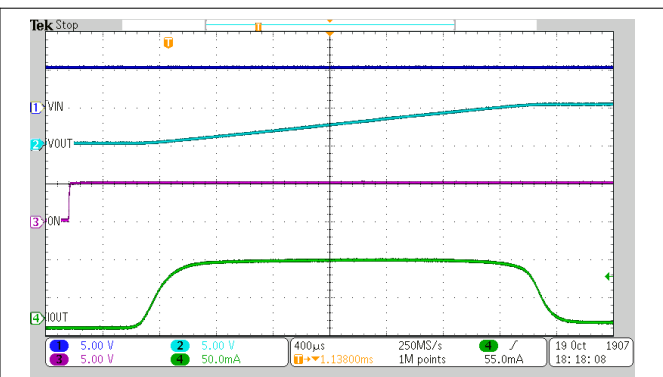


Figure 9-3. Inrush Current for $C_L = 47 \mu\text{F}$ with $CT = 1000 \text{ pF}$

9.3 Power Supply Recommendations

The TPS22995 device is designed to operate with a V_{IN} range of 0.4 V to 5.5 V. The V_{IN} power supply must be well regulated and placed as close to the device terminal as possible. The power supply must be able to withstand all transient load current steps. In most situations, using an input capacitance (C_{IN}) of 1 μF is sufficient to prevent the supply voltage from dipping when the switch is turned on. In cases where the power supply is slow to respond to a large transient load current or large load current step, additional bulk capacitance can be required on the input.

9.4 Layout

9.4.1 Layout Guidelines

For best performance, all traces must be as short as possible. To be most effective, the input and output capacitors must be placed close to the device to minimize the effects that parasitic trace inductances can have on normal operation. Using wide traces for VIN, VOUT, and GND helps minimize the parasitic electrical effects.

9.4.2 Layout Example

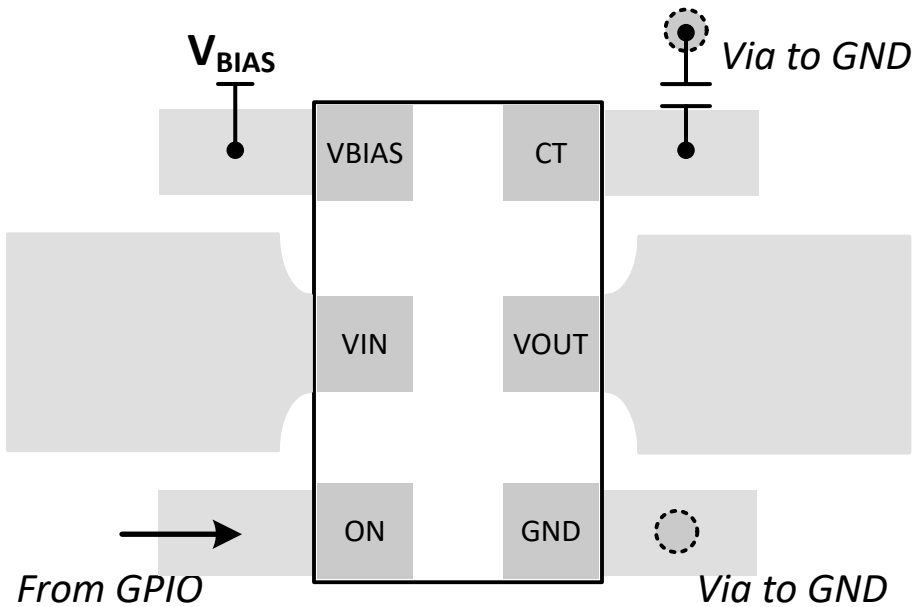


Figure 9-4. Layout Example (RZF, RZG)

10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.2 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

10.3 Trademarks

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All trademarks are the property of their respective owners.

10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

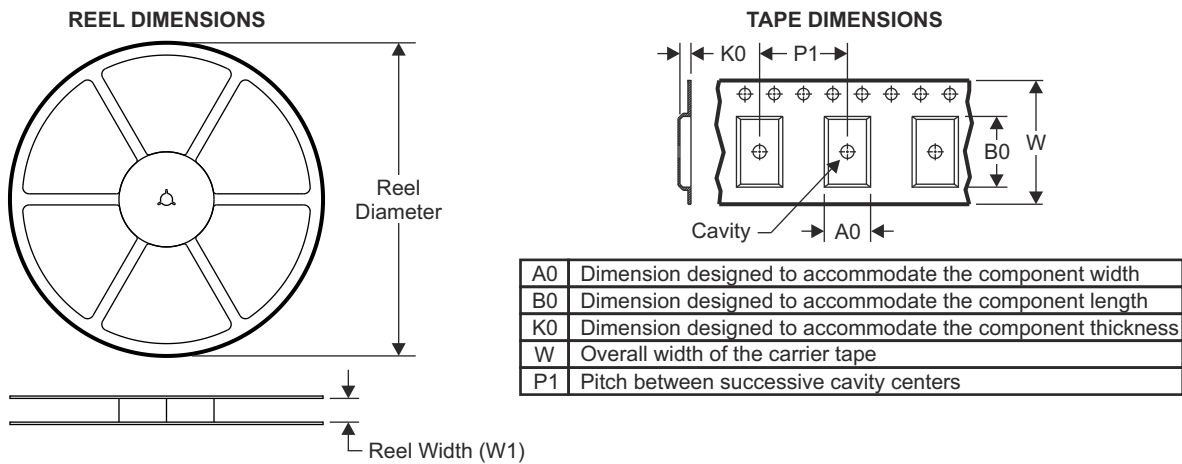
10.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

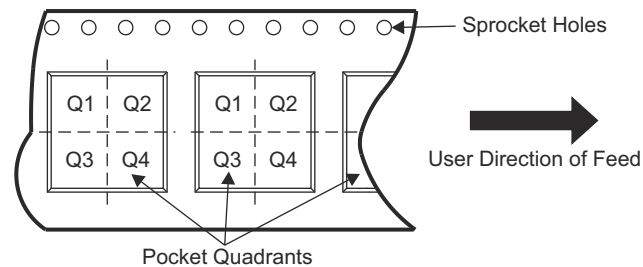
11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

11.1 Tape and Reel Information

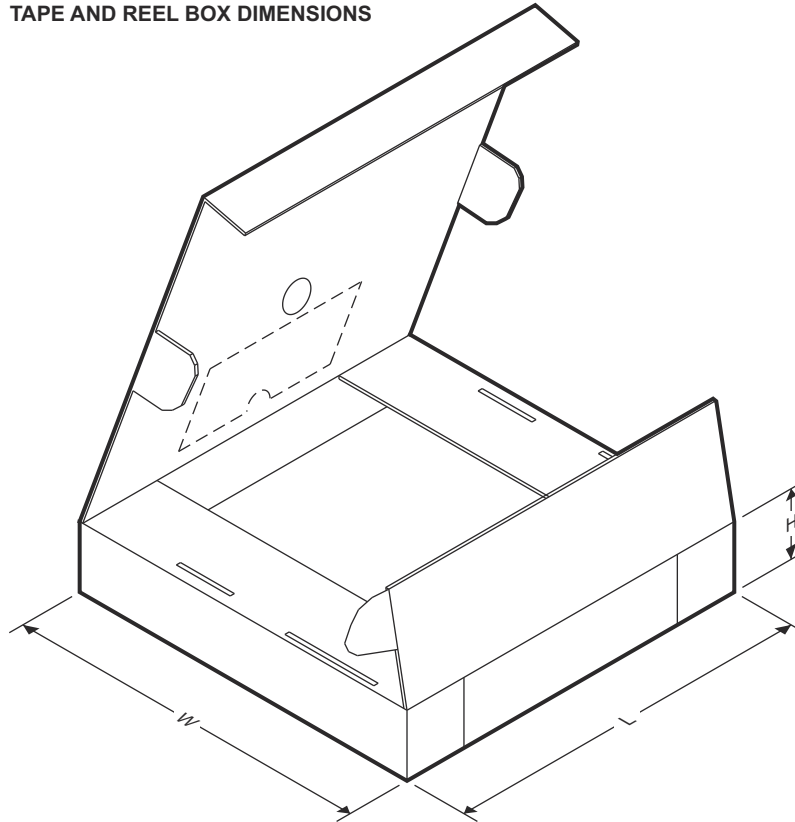


QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22995RZFR	WQFN-HR	RZF	6	3000	180.0	8.4	1.0	1.4	0.88	4.0	8.0	Q1
TPS22995RZGR	WQFN-HR	RZG	6	3000	180.0	8.4	0.9	1.65	0.88	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22995RZFR	WQFN-HR	RZF	6	3000	210.0	185.00	35.0
TPS22995RZGR	WQFN-HR	RZG	6	3000	210.0	185.00	35.0

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS22995RZFR	Active	Production	WQFN-HR (RZF) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	7
TPS22995RZFR.A	Active	Production	WQFN-HR (RZF) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	7
TPS22995RZGR	Active	Production	WQFN-HR (RZG) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	6
TPS22995RZGR.A	Active	Production	WQFN-HR (RZG) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	6

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

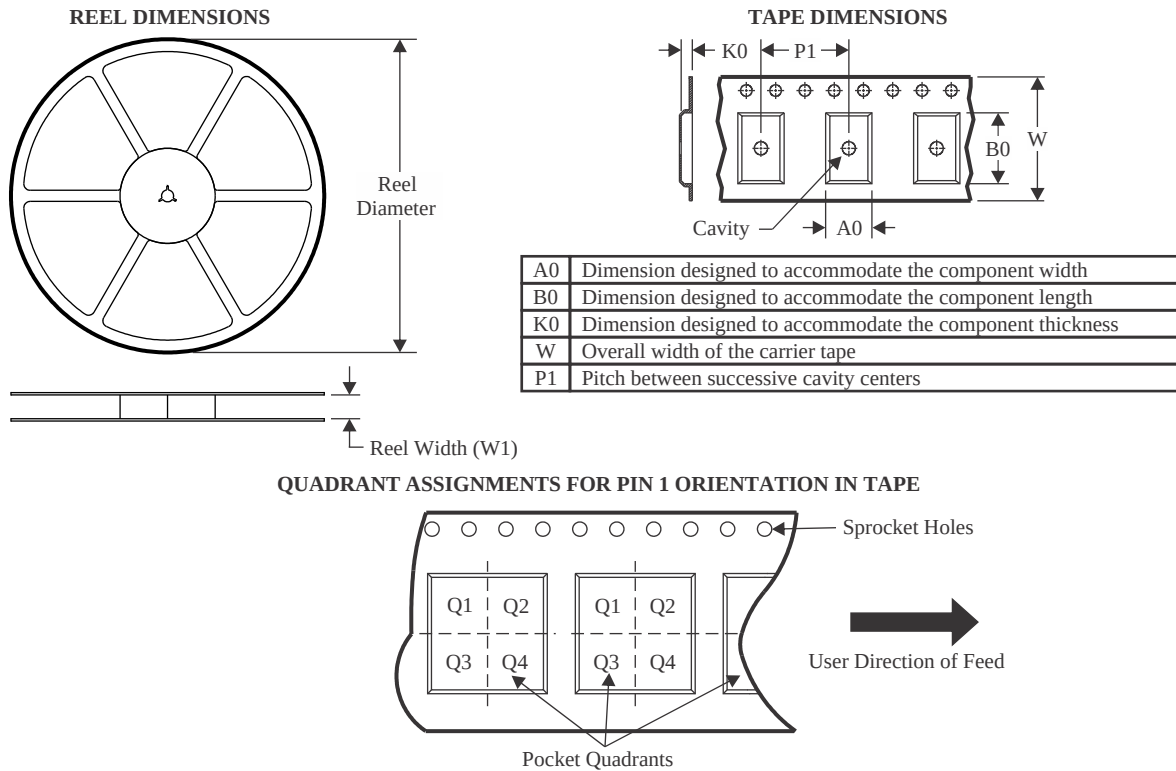
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

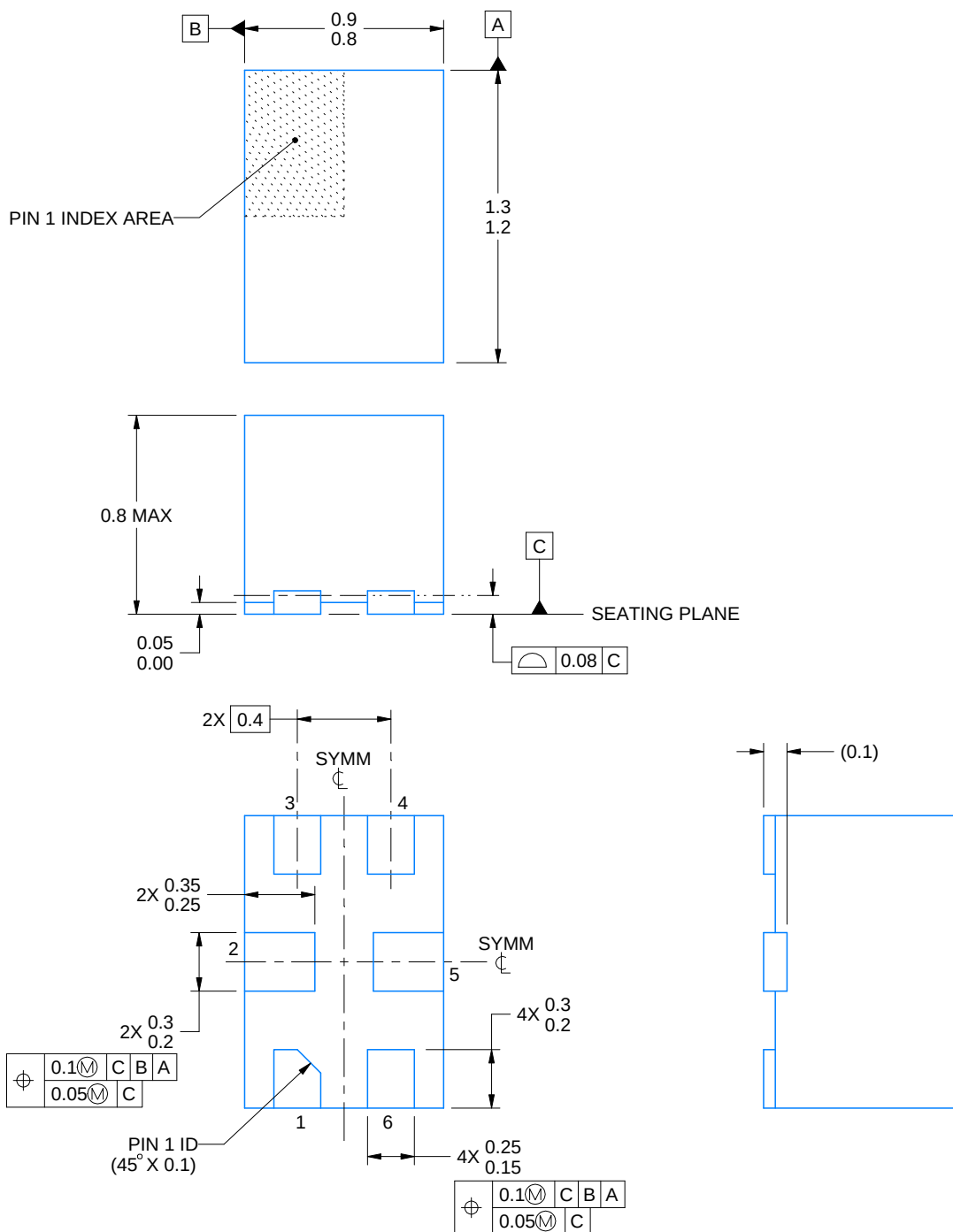
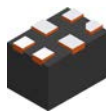
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22995RZFR	WQFN-HR	RZF	6	3000	180.0	8.4	1.0	1.4	0.88	4.0	8.0	Q1
TPS22995RZGR	WQFN-HR	RZG	6	3000	180.0	8.4	0.9	1.65	0.86	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22995RZFR	WQFN-HR	RZF	6	3000	210.0	185.0	35.0
TPS22995RZGR	WQFN-HR	RZG	6	3000	210.0	185.0	35.0



4228215/A 11/2021

NOTES:

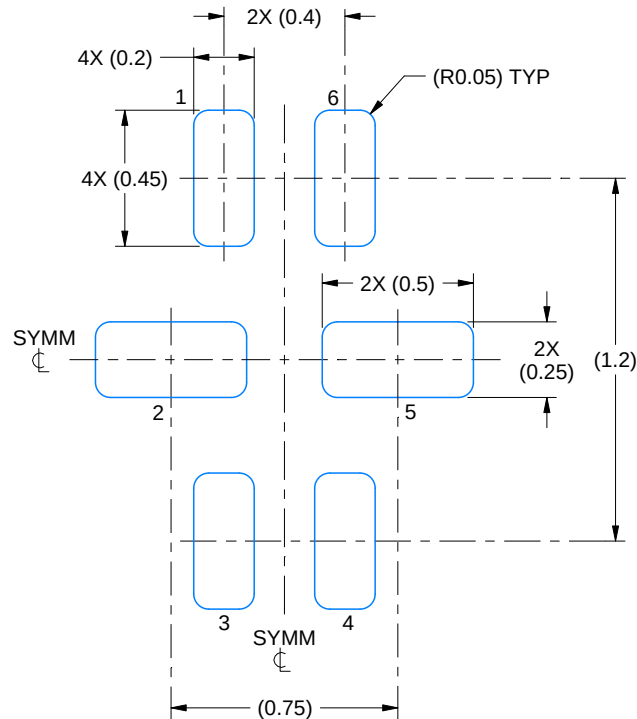
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

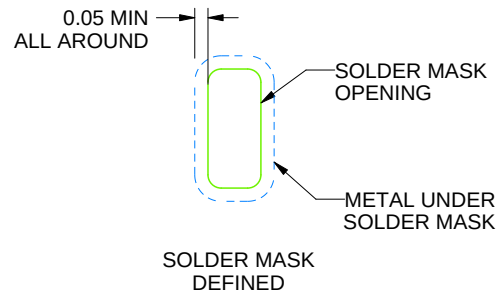
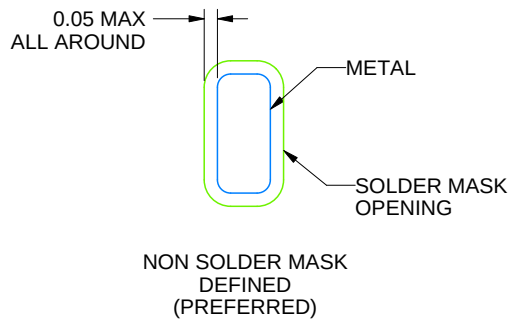
RZF0006A

WQFN - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SCALE:40X



SOLDER MASK DETAILS

4228215/A 11/2021

NOTES: (continued)

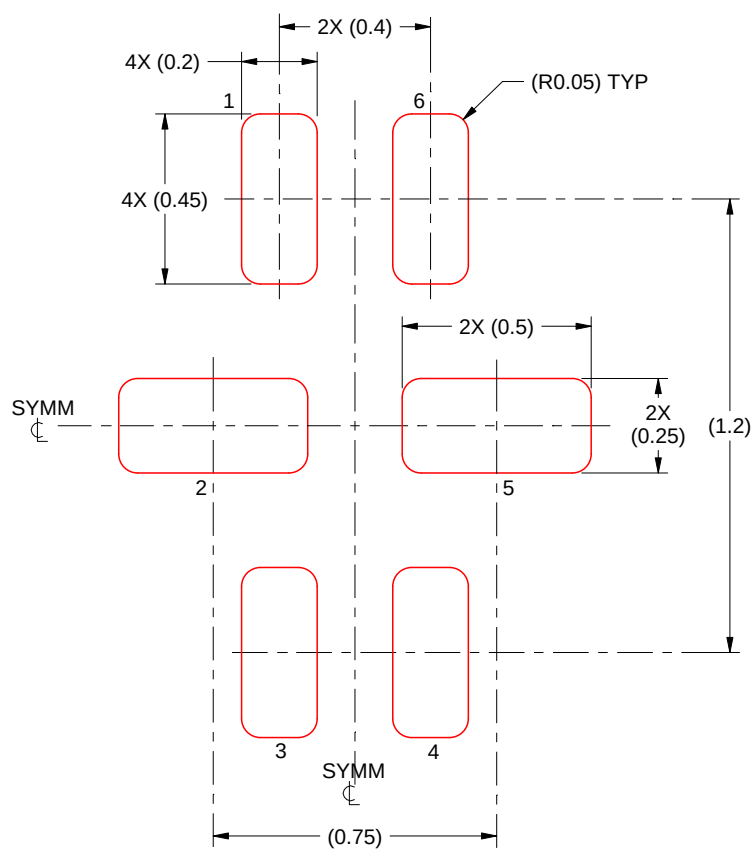
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If all or some are implemented, recommended via locations are shown. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RZF0006A

WQFN - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL

100% PRINTED SOLDER COVERAGE BY AREA
SCALE:50X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

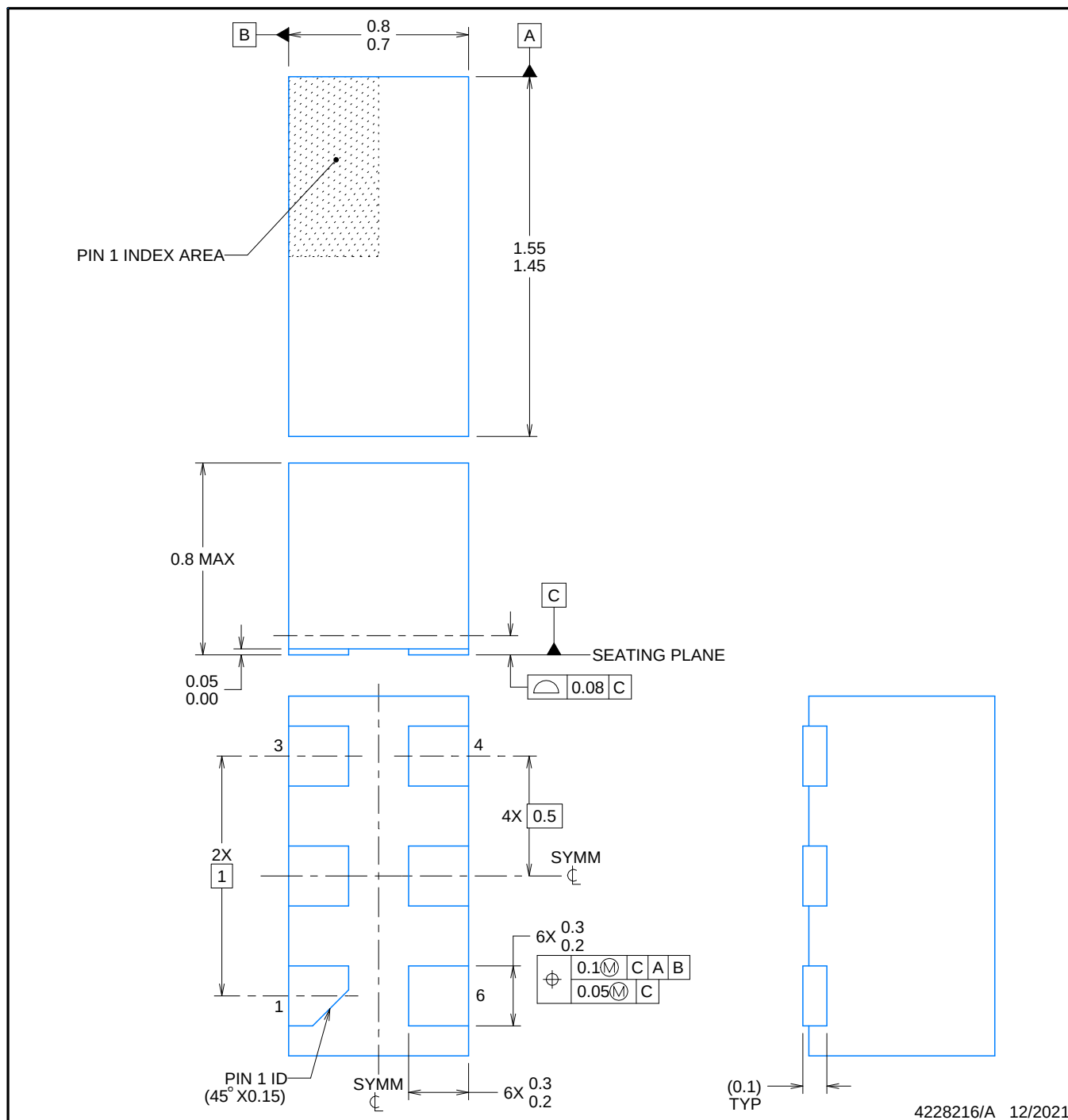


RZG0006A

PACKAGE OUTLINE

WQFN-HR - 0.8mm max height

QFN (PLASTIC QUAD FLATPACK - NO LEAD)



NOTES:

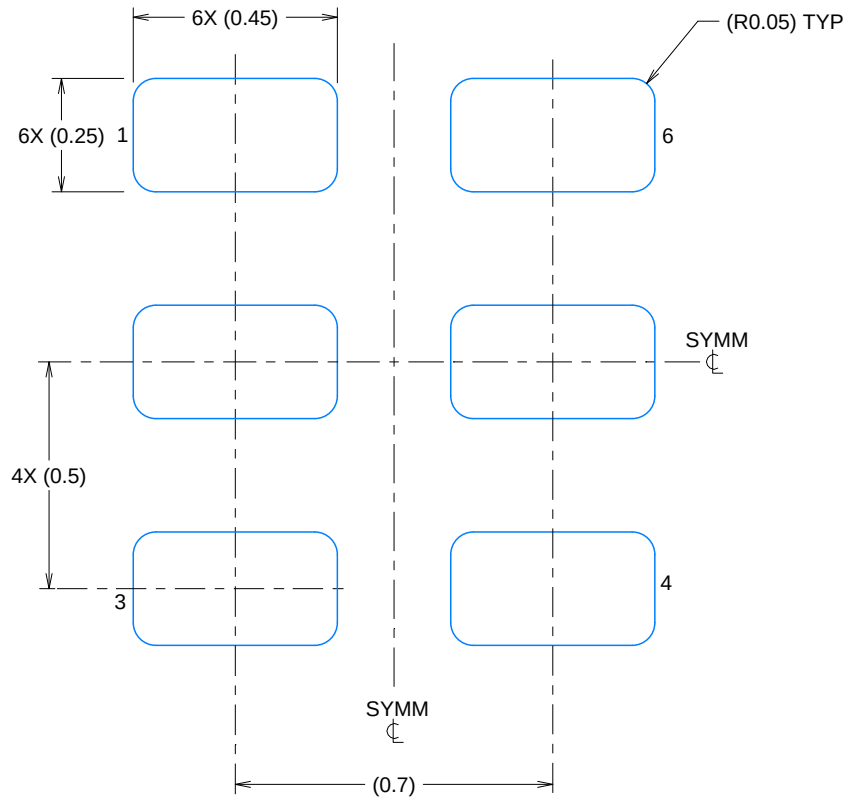
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

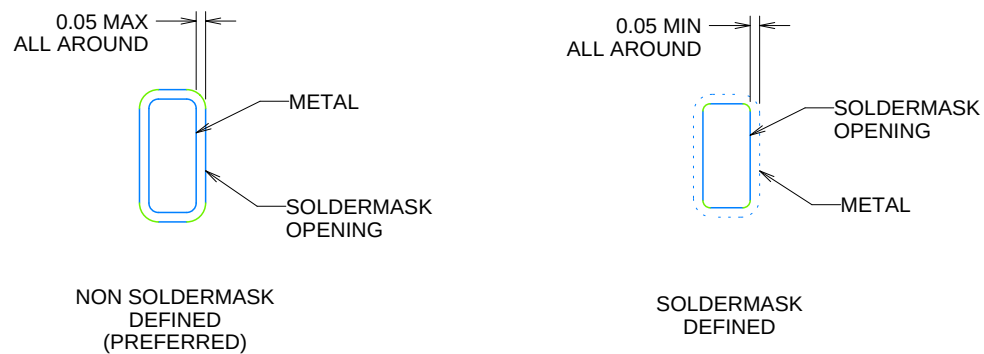
RZG0006A

WQFN-HR - 0.8mm max height

QFN (PLASTIC QUAD FLATPACK - NO LEAD)



LAND PATTERN EXAMPLE
SCALE:60X



SOLDERMASK DETAILS

4228216/A 12/2021

NOTES: (continued)

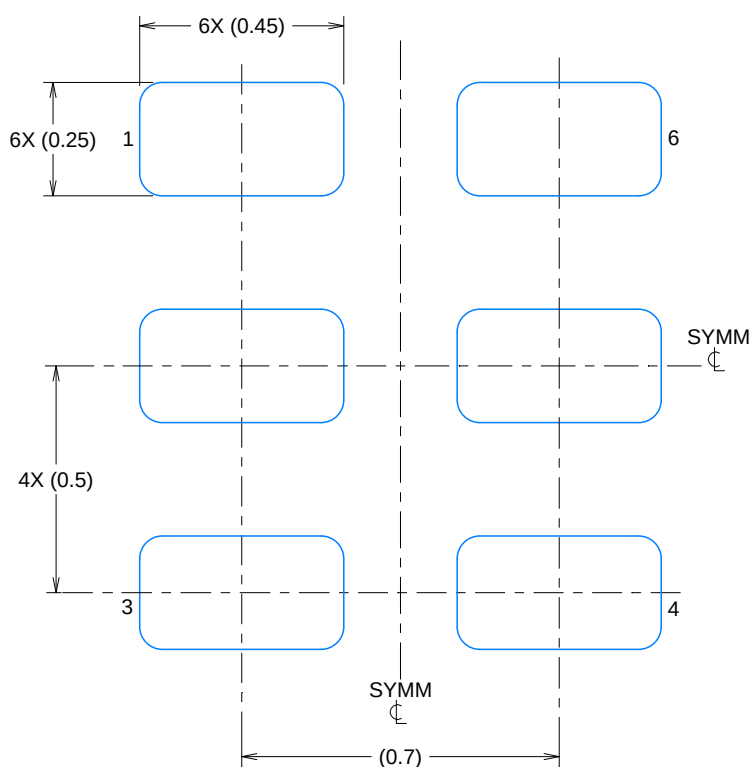
3. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/sluea271).

EXAMPLE STENCIL DESIGN

RZG0006A

WQFN-HR - 0.8mm max height

QFN (PLASTIC QUAD FLATPACK - NO LEAD)



SOLDERPASTE EXAMPLE
BASED ON 0.1mm THICK STENCIL

EXPOSED PAD
100% SOLDER COVERAGE BY AREA
SCALE:60X

4228216/A 12/2021

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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